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SAMTM Data Sheet SAM-1064-8-25ps-x, λ = 1064 nm

Laser wavelength $\lambda = 1064 \text{ nm}$

High reflection band $\lambda = 1020 ... 1110 \text{ nm}$

Absorbance A_0 = 8 % Modulation depth ΔR = 6 % Non-saturable loss A_{ns} = 2 %

Saturation fluence $\Phi_{sat} = 98 \,\mu\text{J/cm}^2$

Relaxation time constant $\tau \sim 27 \text{ ps}$

Damage threshold $\Phi = 2.5 \text{ mJ/cm}^2$

Chip area 4.0 mm x 4.0 mm; other dimensions on request

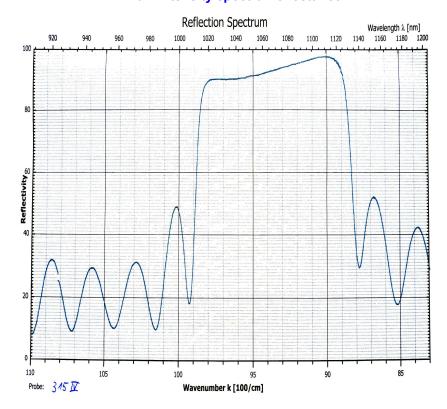
Chip thickness 450 µm

Protection the SAM is protected with a dielectric front layer

Mounting option \mathbf{x} denotes the type of mounting as follows:

$\mathbf{x} = 0$	unmounted
x = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = 25.0 w	soldered on a water cooled Cu-cylinder with 25.0 mm Ø
x = FC	mounted on a 1 m monomode fiber cable with FC connector

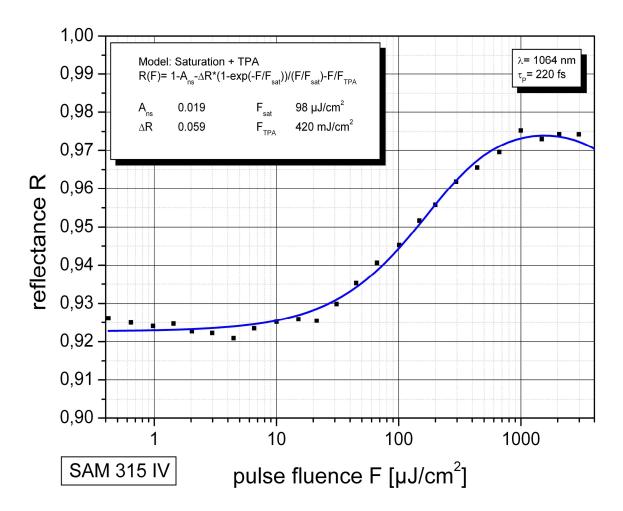
Low intensity spectral reflectance



Data Sheet



Saturation measurement





Pump-probe measurement

